# ANR SPLAM: nouveaux ASUs

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Resistive ASUs

ANR Status

Conclusions

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## Outline

#### Resistive ASUs

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A resistive layer is a resistive coating which produce a distributed R-C network.



The resistivity is given in  $\Omega/\Box$ :  $R = \frac{\rho \cdot l}{h \cdot L}$  with  $L = l \rightarrow R = f(h)$ Common values in PCB manufacturing : 100 k $\Omega/\Box$  to 10 M $\Omega/\Box$ . The capacitance is a function of the dielectric material and its thickness:  $C = \varepsilon_0 \cdot \varepsilon_r \frac{A}{d}$ 

## Orders of magnitude

# Resistivity Layer thickness: 17 to 35 $\mu m.$ Common values in PCB manufacturing: 100 k $\Omega/\Box$ , 1 M $\Omega/\Box$ and 10 M $\Omega/\Box$ .

Capacitance

Common values for  $1 \text{ cm}^2$  anode :

Material	Thickness	Capacitance
Kapton	12.5 µm	240 pF
FR4	50 µm	80 pF
Photoresist	25 µm	100 pF
AriCH <sub>4</sub>	128 µm	20 pF (measured)

## Reminder: current protection



Rp=1 M $\Omega$ , Rs=10  $\Omega$ , Cs=470 pF, D are ON-Semiconductor NUP 4114, Dx are integrated fast diodes.

## Proposition #1

Add a protective layer on the pad à la MAMMA. Implementation studied by Alex, Cyril, Renaud and Rui, presented the 10/01/2012.



## Proposition #1



The myth: the parasitic capacitor ! For a 100  $\mu$ m  $\varnothing$  via with 50  $\mu$ m insulation (worst case !) C<sub>par</sub><0.5 pF. Mesh pillar over the via to ensure regular field (anyway, the via is grounded and not necessary over the R layer).

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## Proposition #2

### Perform a pure capacitive readout. cf. R&D with BC16T.

## copper anode



Unrealistic without ceramic-loaded films (loss of signal too important). Expensive and film not easy to stock up (need license agreement...).

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## Charge vs Cs vs Cdet



Signal transfert ratio vs Cdet and Cprot

## Charge vs Cs



Charge transfert as a function of Cprot

## Proposition 3

À la COMPASS: same as #1, but R layer is discharged via FE. resistive layer silkscreen resistor photoresist copper pad Cdet

## Simulation of #1



## Simulation of #3



### Pro and con

Simulation results very similar, but for both case, R and C must be tuned.

Solution Mamma	Solution COMPASS		
pro	con	pro	con
should work	sophisticated vias	easy	dead time
K at 0V possible			noisy?

Mamma (32x48) already designed by Alex (2217E + 1200E tool + postprocess: 2100 CHF/pièce + 600 CHF tool) Possible to test via connection (different configuration) for 1700 CHF (all included) Compass possible with existing ASU (postprocess: 4000 CHF for 2 boards)

## Big vs small

### Small

- Small prototype may help to test via connection for 1st solution, but there is another way, quickest and less expensive.
- Risk to be dominated by edge effect  $\rightarrow$  if small proto are choosen, perhaps 16x16 is much better than 8x8.

### Full size

- All ASU design already done  $\rightarrow$  quickest and separate potential problems (same routing, etc)
- No new interdif (design time + pcb cost + new tools for cabling)
- No software nor firmware modification
- Result can be compared directly and immediately to square meter ASUs
- More than 300 MICROROC remaining.

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## Simulations

Well engaged, but we need to extract parameters from a prototype!. Then only we'll be able to ensure accuracy of simulations. Values are at the moment "orders of magnitude", mix of theory and rough measurement : we'll use resistive prototype to extract some values.

### Protections tests

Jérôme has successfully tested a first batch of the new silicon protective structures (diode+MOS). The comparison with the reference protection has not been done yet, because the reference structure does not work yet... Investigation on the way!

### Funds

Allocated by ANR (excluding Jérôme's contract): 51 500 € Bonus from Arves Industries : 7 564 € Total : 59 064 € Remaining : 43 271 €

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- According to me, both solutions (MAMMA and COMPASS) are appealing and both should be tested
- Do not forget that we want to build large detector in fine
- Jerôme's contract ends this year : big prototype are quicker to build, and the cost is not so much higher
- Big prototype will help us to refine modelling.